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Title: METHODS FOR PRESERVING STRAINED SEMICONDUCTOR SUBSTRATE LAYERS DURING CMOS PROCESSING Inventors: Currie et al. Serial No. 10/696,994 Atty Docket No.: ASC-063 Attorney for Applicants: Mark L. Beloborodov Sheet 3 of 4 REPLACEMENT SHEET

560

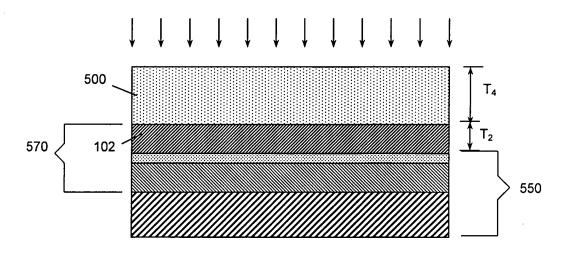


FIG. 2A

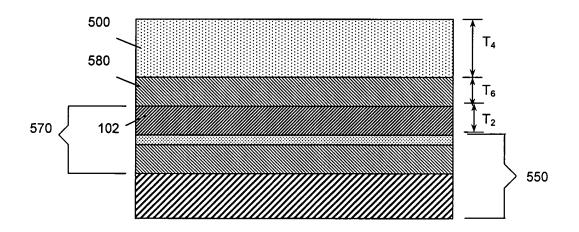


FIG. 2B

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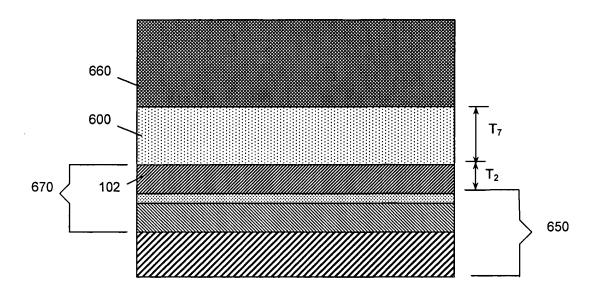


FIG. 3A

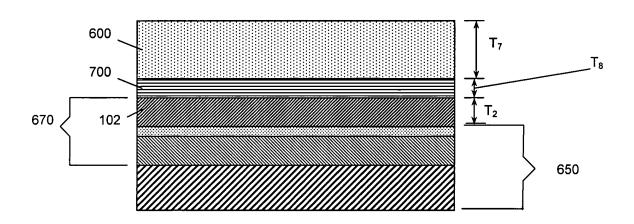


FIG. 3B